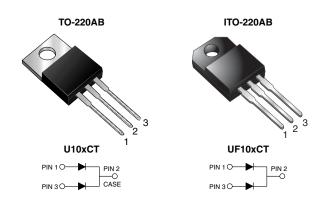
U(F,B)10BCT thru U(F,B)10DCT



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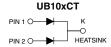
COMPLIANT

Dual Common-Cathode Ultrafast Rectifier



TO-263AB





PRIMARY CHARACTERISTICS					
I _{F(AV)}	5 A x 2				
V_{RRM}	100 V, 150 V, 200 V				
I _{FSM}	55 A				
t _{rr}	25 ns				
V_{F}	0.89 V				
T _J max.	150 °C				

FEATURES

- · Oxide planar chip junction
- · Ultrafast recovery time
- Soft recovery characteristics
- · Low switching losses, high efficiency
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 260 °C, 40 s (for TO-220AB, IT-220AB)
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching power supplies, freewheeling diodes, dc-to-dc converters or polarity protection application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB and TO-263AB Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class

1A whisker test **Polarity:** As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted)							
PARAMETER		U(F,B)10BCT U(F,B)10CCT		U(F,B)10DCT	UNIT		
Maximum repetitive peak reverse voltage	V_{RRM}	100	150	200	٧		
Max. average forward rectified current (Fig. 1) total device per diode	I _{F(AV)}	10 5			Α		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}	55			Α		
Electrostatic discharge capacitor voltage, human body model: C = 150 pF, R = 1.5 k Ω (contact mode)	V _C	8			kV		
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min per diode	V _{AC}	1500			V		
Operating junction and storage temperature range	T _J , T _{STG}	- 55 to + 150			°C		

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ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Maximum instantaneous forward voltage per diode ⁽¹⁾	I _F = 3.0 A I _F = 5.0 A	T _J = 25 °C	· V _F	0.97 1.05	- 1.10	· v	
	I _F = 3.0 A I _F = 5.0 A	T _J = 150 °C		0.79 0.89	- 0.95		
Maximum reverse current per diode (2)	rated V _R	$T_J = 25$ °C $T_J = 100$ °C	I _R	0.5 100	5.0 200	μΑ	
Maximum various recovers time nov diade	I _F = 0.5 A, I _R = 1.0 A, I _{rr} = 0.25 A		t _{rr}	13	20	ns	
Maximum reverse recovery time per diode	$I_F = 1.0 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s},$ $V_R = 30 \text{ V}, I_{rr} = 0.1 I_{RM}$			19.7	25		
Maximum stored charge per diode	$I_F = 2 \text{ A}, \text{ dI/dt} = 20 \text{ A/}\mu\text{s},$ $V_R = 30 \text{ V}, I_{rr} = 0.1 I_{RM}$		Q _{rr}	3	9	nC	

Notes

(1) Pulse test: 300 μ s pulse width, 1 % duty cycle

(2) Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	U10xCT	UF10xCT	UB10xCT	UNIT
Typical thermal resistance per diode	$egin{aligned} R_{ hetaJA}\ R_{ hetaJC} \end{aligned}$	25 5.3	25 7.5	25 5.3	°C/W

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	U10DCT-E3/4W	1.87	4W	50/tube	Tube		
ITO-220AB	UF10DCT-E3/4W	1.77	4W	50/tube	Tube		
TO-263AB	UB10DCT-E3/4W	1.31	4W	50/tube	Tube		
TO-263AB	UB10DCT-E3/8W	1.31	8W	800/reel	Tape and reel		



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RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

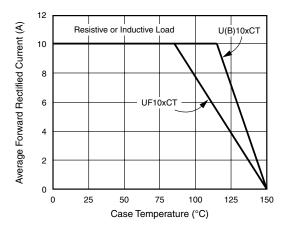


Figure 1. Maximum Forward Current Derating Curve

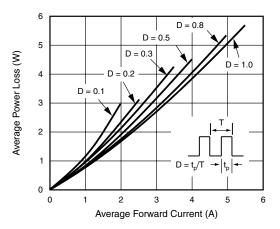


Figure 2. Forward Power Loss Characteristics Per Diode

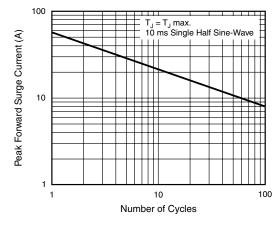


Figure 3. Maximum Non-Repetitive Peak Forward Surge Current Per Diode

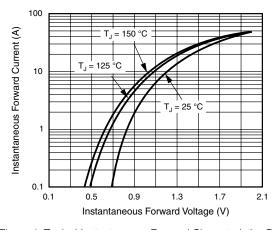


Figure 4. Typical Instantaneous Forward Characteristics Per Diode

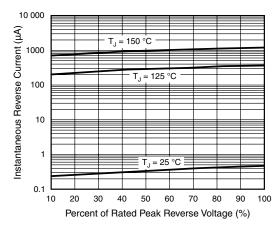


Figure 5. Typical Reverse Characteristics Per Diode

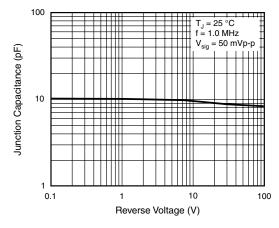


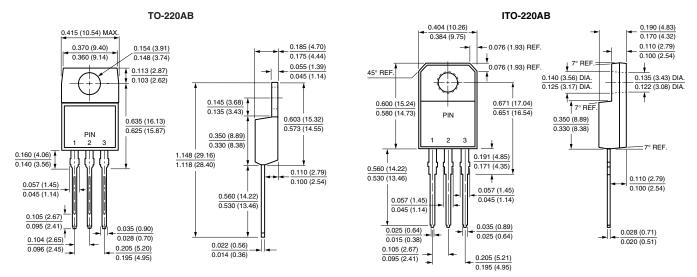
Figure 6. Typical Junction Capacitance Per Diode

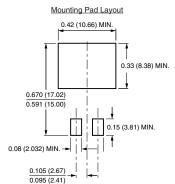
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





TO-263AB



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